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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR $\mu$ PA2731T1A

### **SWITCHING** P-CHANNEL POWER MOSFET

#### **DESCRIPTION**

The  $\mu$  PA2731T1A is P-channel MOS Field Effect Transistor designed for power management applications of notebook computers and Li-ion battery protection circuit.

#### **FEATURES**

Low on-state resistance

 $R_{DS(on)1} = 3.3 \text{ m}\Omega \text{ MAX}. \text{ (V}_{GS} = -10 \text{ V}, I_{D} = -22 \text{ A})$ 

 $R_{DS(on)2} = 6.4 \text{ m}\Omega \text{ MAX.} (V_{GS} = -4.5 \text{ V}, I_{D} = -22 \text{ A})$ 

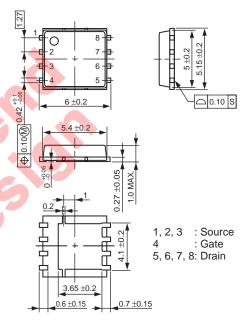
- Low Ciss: Ciss = 3620 pF TYP.
- Built-in gate protection diode
- Small and surface mount package (8pin HVSON)

#### ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA2731T1A-E1-AZ <sup>Note</sup>	8pin HVSON
μ PA2731T1A-E2-AZ <sup>Note</sup>	8pin HVSON

Note Pb-free (This product does not contain Pb in external electrode.)

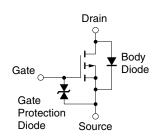
#### PACKAGE DRAWING (Unit: mm)



#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	VDSS	-30	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC)	ID(DC)	<b>∓44</b>	Α
Drain Current (pulse) Note1	ID(pulse)	∓180	Α
Total Power Dissipation Note2	P <sub>T1</sub>	1.5	W
Total Power Dissipation (PW = 10 sec) Note2	P <sub>T2</sub>	4.6	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note3	las	-22	Α
Single Avalanche Energy Note3	Eas	48	mJ

#### **EQUIVALENT CIRCUIT**



- **Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%
  - 2. Mounted on a glass epoxy board (25.4 mm x 25.4 mm x 0.8 mm)
  - 3. Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = -15 V, R<sub>G</sub> = 25  $\Omega$ , L = 100  $\mu$ H, V<sub>GS</sub> = -20  $\rightarrow$  0 V

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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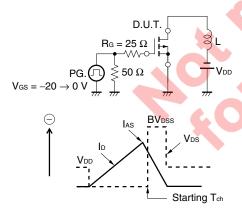


### **ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)**

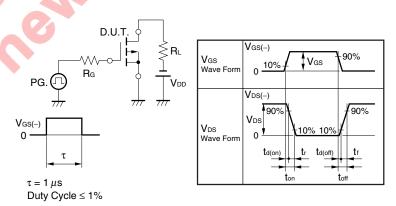
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = -30 V, V <sub>GS</sub> = 0 V			-1	μA
Gate Leakage Current	Igss	$V_{GS} = \mp 20 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.0		-2.5	<b>V</b>
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -22 A		2.6	3.3	mΩ
	RDS(on)2	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -22 A		4.2	6.4	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = -10 V		3620		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		1540		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		630		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = -15 V, I <sub>D</sub> = -22 A		15		ns
Rise Time	<b>t</b> r	V <sub>GS</sub> = -10 V		16		ns
Turn-off Delay Time	<b>t</b> d(off)	R <sub>G</sub> = 10 Ω		760		ns
Fall Time	t <sub>f</sub>			510		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = -24 V		149		nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = -10 V		17		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = -44 A		48		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 44 A, V <sub>GS</sub> = 0 V		0.85		V
Reverse Recovery Time	trr	I <sub>F</sub> = 44 A, V <sub>GS</sub> = 0 V		87		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		60		nC

Note Pulsed

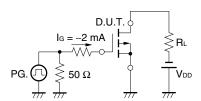
#### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**



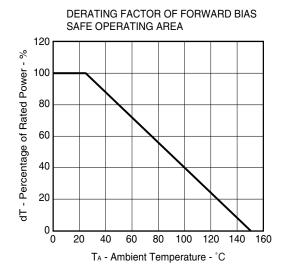
#### **TEST CIRCUIT 2 SWITCHING TIME**



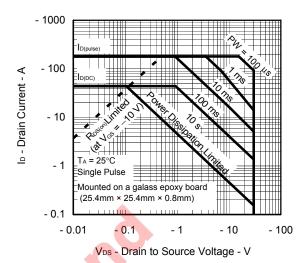
#### **TEST CIRCUIT 3 GATE CHARGE**



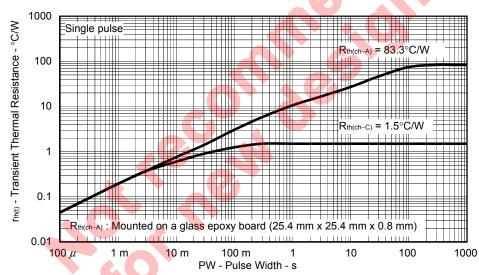
### TYPICAL CHARACTERISTICS (TA = 25°C)



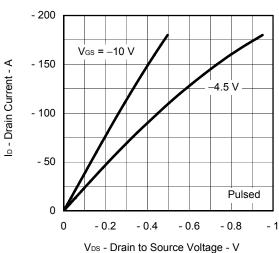
#### FORWARD BIAS SAFE OPERATING AREA



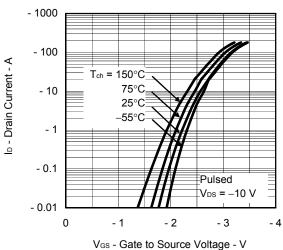
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



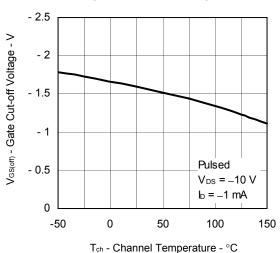
#### DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



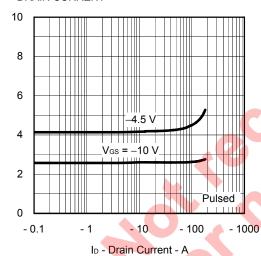
#### FORWARD TRANSFER CHARACTERISTICS



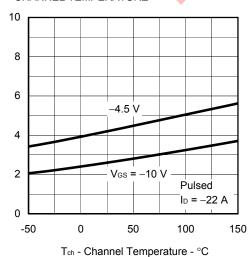
# GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



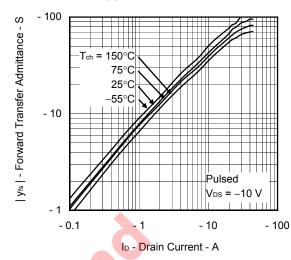
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



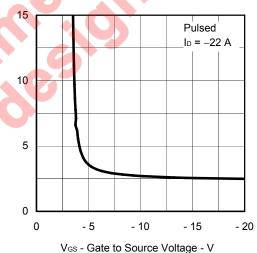
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



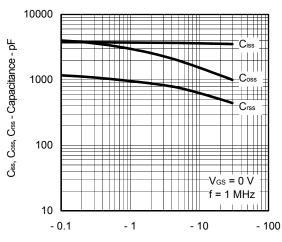
### FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



# DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



#### CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



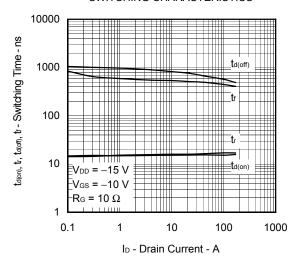
V<sub>DS</sub> - Drain to Source Voltage - V

R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ

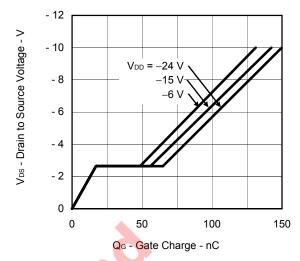
RDS(on) - Drain to Source On-state Resistance - m\Omega

R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

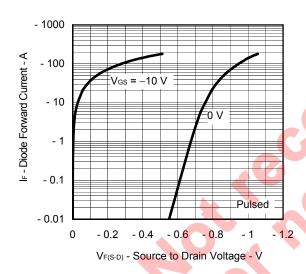
#### SWITCHING CHARACTERISTICS



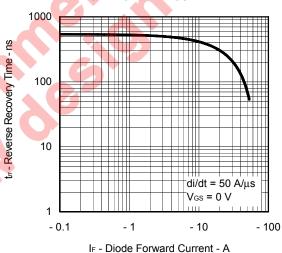
#### DYNAMIC INPUT CHARACTERISTICS



#### SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



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